

BCR12CM-16LH

Triac Medium Power Use

R07DS0261EJ0100 Rev.1.00 Mar 09, 2011

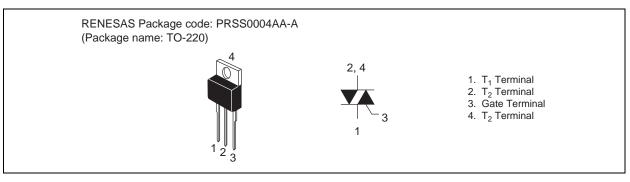
Datasheet

Features

- I_{T (RMS)} : 12 A
- V_{DRM} : 800 V
- I_{FGTI} , I_{RGTI} , $I_{RGT III}$: 50 mA or 35mA(I_{GT} item:1)
- High Commutation

- The Product guaranteed maximum junction temperature 150°C
- Planar Type

Outline



Applications

Switching mode power supply, motor control, heater control, and other general purpose AC power control applications

Maximum Ratings

Parameter	Symbol	Voltage class	Unit
Farameter	Symbol	16	Unit
Repetitive peak off-state voltage ^{Note1}	V _{DRM}	800	V
Non-repetitive peak off-state voltage ^{Note1}	V _{DSM}	960	V

Notes: 1. Gate open.

Parameter	Symbol	Ratings	Unit	Conditions
RMS on-state current	I _{T (RMS)}	12	A	Commercial frequency, sine full wave 360° conduction, Tc = 123° C ^{Note3}
Surge on-state current	I _{TSM}	120	A	60 Hz sinewave 1 full cycle, peak value, non-repetitive
I ² t for fusion	l ² t	60	A ² s	Value corresponding to 1 cycle of half wave 60 Hz, surge on-state current
Peak gate power dissipation	P _{GM}	5	W	
Average gate power dissipation	P _{G (AV)}	0.5	W	
Peak gate voltage	V _{GM}	10	V	
Peak gate current	I _{GM}	2	А	
Junction Temperature	Tj	-40 to +150	°C	
Storage temperature	Tstg	-40 to +150	°C	
Mass	_	2.0	g	Typical value



Parameter			BCR12CM-16LH-1		BCR12CM-16LH			Unit	Test conditions	
		Symbol	(I _{GT} item: 1)							
		-	Min.	Тур.	Max.	Min.	Тур.	Max.		
Repetitive peak off-state co	urrent	I _{DRM}			2.0		_	2.0	mA	Tj = 150°C V _{DRM} applied
On-state voltage		V _{TM}		_	1.5		—	1.5	V	$Tc = 25^{\circ}C$, $I_{TM} = 20 A$ instantaneous measurement
Gate trigger voltage ^{Note2}	Ι	—		_	1.5	—	—	1.5	V	$Tj = 25^{\circ}C, V_{D} = 6 V$
	II	—	_	_	1.5	—	—	1.5	V	$R_L=6~\Omega,~R_G=330~\Omega$
	III	—	—	_	1.5	—	—	1.5	V	
Gate trigger curent ^{Note2}	Ι	—		_	35	_		50	mA	$Tj = 25^{\circ}C, V_{D} = 6 V$
	II	—		_	35	_		50	mA	$R_L=6~\Omega,~R_G=330~\Omega$
	III	—	—	_	35	_	—	50	mA	
Gate non-trigger voltage		V _{GD}	0.2			0.2	—		V	Tj = 125°C V _D = 1/2 V _{DRM}
			0.1	_	_	0.1	—	_	V	Tj = 150°C V _D = 1/2 V _{DRM}
Thermal resistance		R _{th (j-c)}	_	—	1.8	—		1.8	°C/W	Junction to case ^{Note3,4}
Critical-rate of decay of on commutating current Note5	-state	(di/dt)c	7	_	_	13	—	—	A/ms	Tj = 125°C (dv/dt)c < 100 V/μs

Electrical Characteristics

Notes: 2. Measurement using the gate trigger characteristics measurement circuit.

3. Case temperature is measured at the T_2 tab 1.5 mm apart from the molded case.

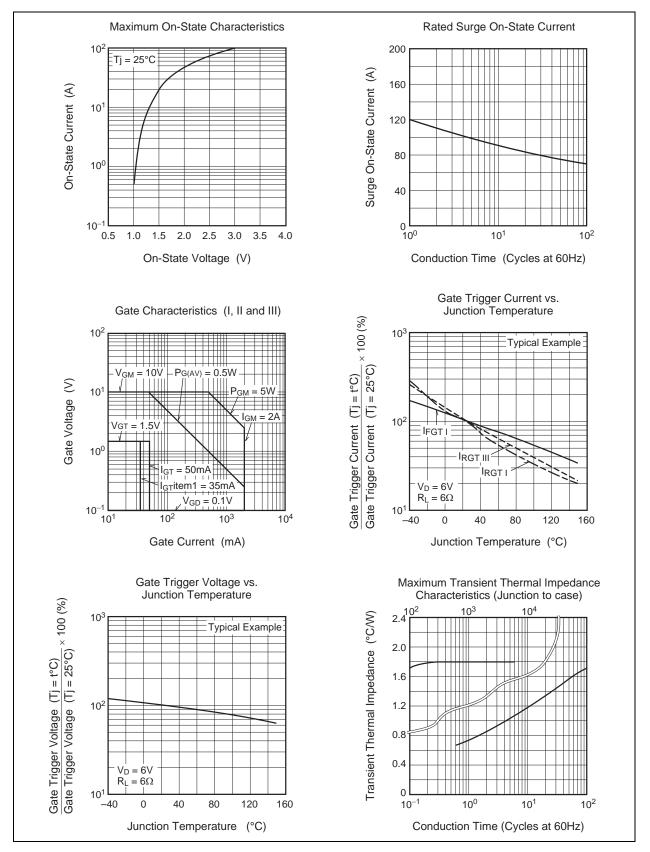
4. The contact thermal resistance $R_{th \, (c\text{-}f)}$ in case of greasing is 1.0°C/W.

5. Test conditions of the critical-rate of decay of on-state commutation current are shown in the table below.

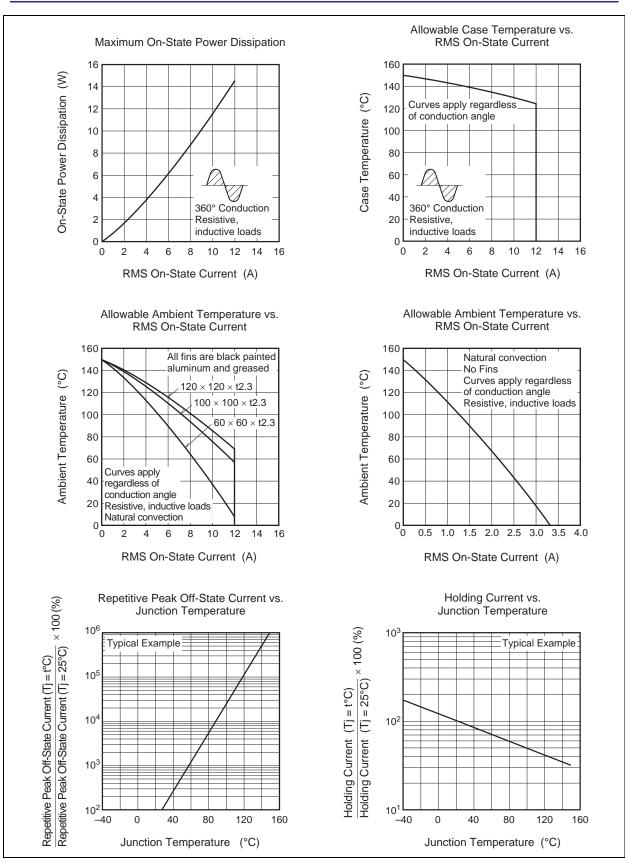
Test conditions	Commutating voltage and current waveforms (inductive load)				
1. Junction temperature Tj = 125°C	Supply Voltage → Time				
2. Peak off-state voltage $V_D = 400 \text{ V}$	Main Current → Time				
2. Rate of rise of off-state commutating voltage (dv/dt)c < 100 V/ μ s	Main Voltage				

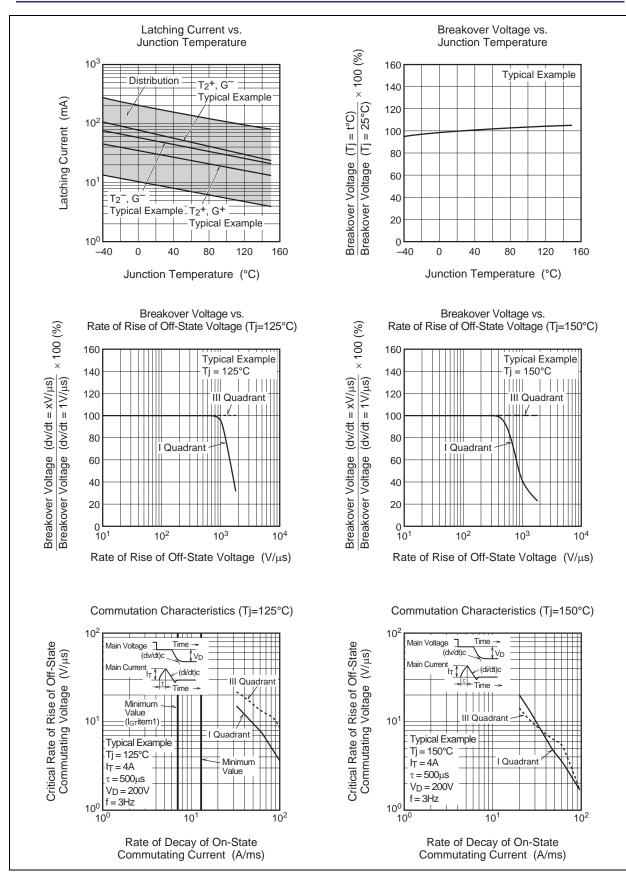


Performance Curve

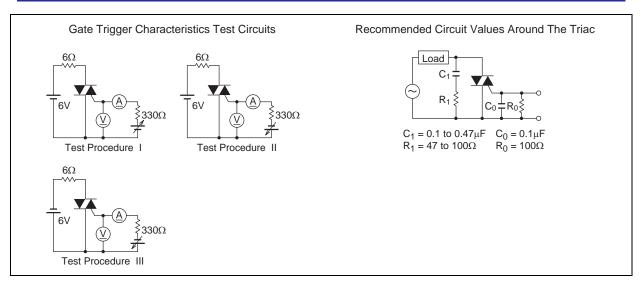






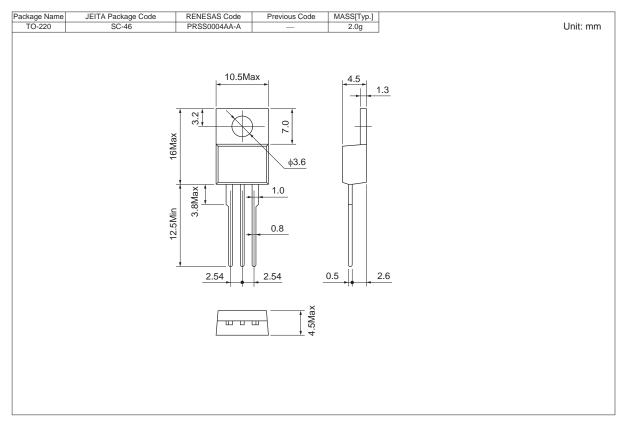


R07DS0261EJ0100 Rev.1.00 Mar 09, 2011





Package Dimensions



Ordering Information

Orderable Part Number	Packing	Quantity	Remark
BCR12CM-16LH#B00	Bag	100 pcs.	Straight type
BCR12CM-16LH-1#B00	Bag	100 pcs.	Straight type, I _{GT} item:1

Note : Please confirm the specification about the shipping in detail.



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Renesas Electronics Corporation

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 Renesas Electronics America Inc.

 2880 Scott Bouldshard Santa Clara, CA 95050-2554, U.S.A.

 Tel: +1-408-5884000, Fax: +1-408-588-6130

 Renesas Electronics Canada Limited

 1101 Nicholson Road, Newmarket, Ontario L3Y 9C3, Canada

 Tel: +1-905-898-6441, Fax: +1-905-898-5320

 Renesas Electronics Curpe Limited

 Dukes Meadow, Milboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K

 Tel: +44-1628-585-100, Fax: +44-1628-586-900

 Renesas Electronics Europe GmbH

 Arcadiastrasse 10, 40472 Düsseldorf, Germany

 Tel: +49-21-56303, Fax: +40-211-56303, Tax: +40-211-65031-1327

 Renesas Electronics (China) Co., Ltd.

 Thi Floor, Ouantum Plaza, No.27 Zh/ChunLu Haldian District, Beijing 100083, P.R.China

 Tel: +86-10-8235-1155, Fax: +86-10-8235-7679

 Renesas Electronics (Shanghai) Co., Ltd.

 Unit 204, 205, AZIA Center, No.1233 Lujiazui Ring Rd., Pudong District, Shanghai 200120, China

 Tel: +86-21-5877-1818, Fax: +86-21-6807-7880

 Renesas Electronics Mong Kong Limited

 Unit 101-1131, 161-F, Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong

 Tel: +86-24805-9318, Fax: +86-214-6897-7869

 Renesas Electronics Taiwan Co., Ltd.

 13F, No. 465, Furshing Name, Taipei, Taiwan

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